

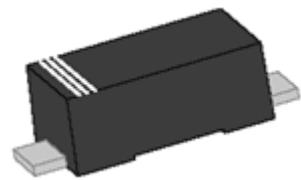


P0641DM TSS

Rev.1.0

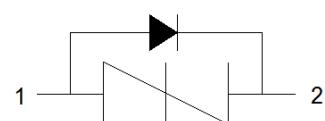
DESCRIPTION:

P0641DM devices are a type of semiconductor component. They are designed to protect base band equipment from damaging overvoltage transients.



FEATURES:

- ✧ Excellent capability of absorbing transient surge.
- ✧ Quick response to surge voltage (ns Level).
- ✧ Eliminates overvoltage caused by fast rising transients.
- ✧ Moisture sensitivity level: Level 1.
- ✧ Non degenerative.



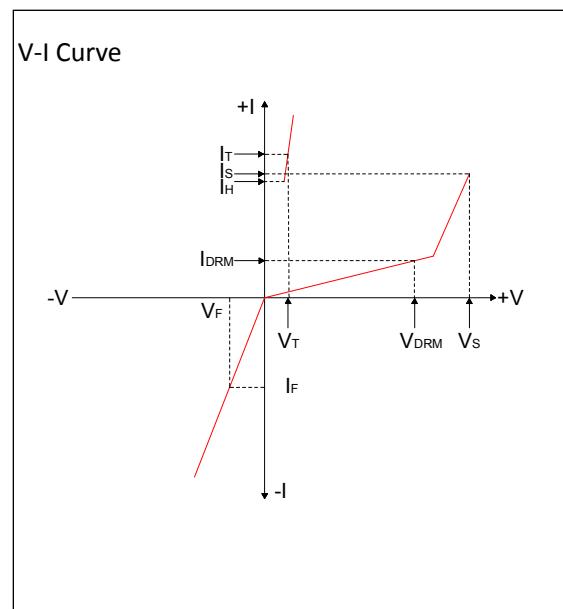
Symbol

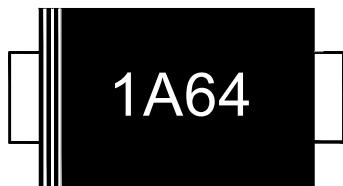
ABSOLUTE MAXIMUM RATINGS ($T_A=25^\circ\text{C}$, RH=45%-75%, unless otherwise noted)

Parameter	Symbol	Value	Unit
Storage temperature range	T_{STG}	-60 to +150	°C
Operating junction temperature range	T_J	-40 to +125	°C
Repetitive peak pulse current@10/1000μs	I_{PP}	35	A

ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$)

Symbol	Parameter
V_{DRM}	Peak off-state voltage
I_{DRM}	Off-state current
V_s	Switching voltage
I_s	Switching current
V_T	On-state voltage
I_T	On-state current
I_H	Holding current
C_O	Off-state capacitance
V_F	Forward voltage



MARKING

1A64 : Device Marking Code

ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$, continued)

Part Number	$I_{DRM} @ V_{DRM}$ PIN2-1		$V_S @ I_S$ PIN2-1		$V_T @ I_T$ PIN2-1		I_H PIN2-1	$V_F @$ $I_F = 10\text{mA}$ PIN1-2	$C_O @$ Marking	
	μA	V	V	mA	V	A	mA	V		
	max	min	max	max	max	max	min	max		
P0641DM	1	60	80	200	4.0	2.2	100	2.0	100	1A64

(1) V_S is measured at 100KV/s(2) Off-state capacitance is measured in $V_{DC}=2\text{V}$, $V_{RMS}=1\text{V}$, $f=1\text{MHz}$ **SURGE RATINGS**

Series	$I_{PP}(\text{A}) \text{ min}$			
	2/10 μs	8/20 μs	10/360 μs	10/1000 μs
M	100	90	50	35

ORDERING INFORMATION

P	064	1	D	M
Series code P: SIDAC				Surge ratings: 2.0KV(10/700 μs)
Median voltage				Package type: SOD-123FL

1: Uni-direction

SOLDERING PARAMETERS

Reflow Condition		Pb-Free assembly (see FIG.2)
Pre Heat	-Temperature Min ($T_{s(\min)}$)	+150 °C
	-Temperature Max($T_{s(\max)}$)	+200 °C
	-Time (Min to Max) (t_s)	60-180 secs.
Average ramp up rate (Liquidus Temp (T_L)to peak)		3 °C/sec. Max
$T_{s(\max)}$ to T_L - Ramp-up Rate		3 °C/sec. Max
Reflow	-Temperature(T_L) (Liquidus)	+217 °C
	-Temperature(t_L)	60-150 secs.
Peak Temp (T_p)		+260(+0/-5) °C
Time within 5 °C of actual Peak Temp (t_p)		30 secs. Max
Ramp-down Rate		6 °C/sec. Max
Time 25 °C to Peak Temp (T_p)		8 min. Max
Do not exceed		+260 °C

FIG.1: $tr \times td$ pulse waveform

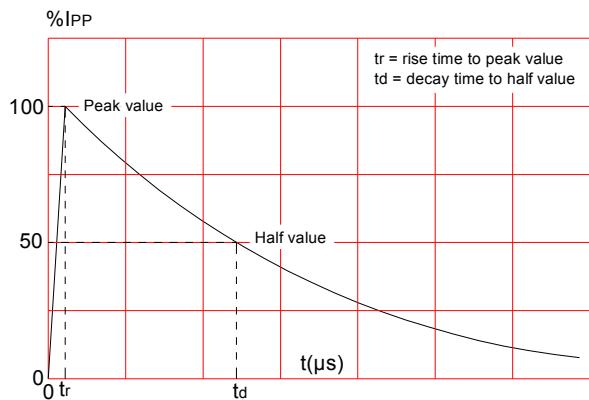


FIG.3: Normalized Vs change vs. junction temperature

FIG.2: Reflow condition

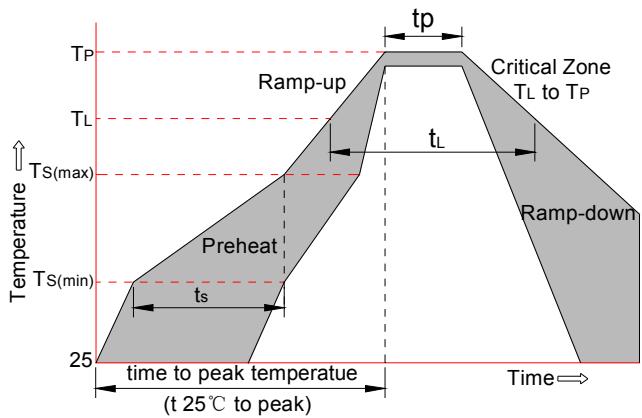
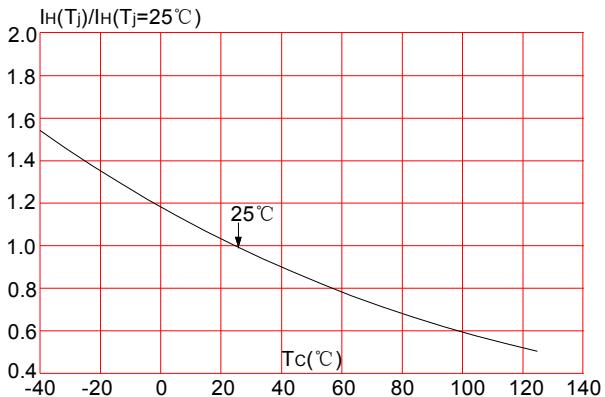
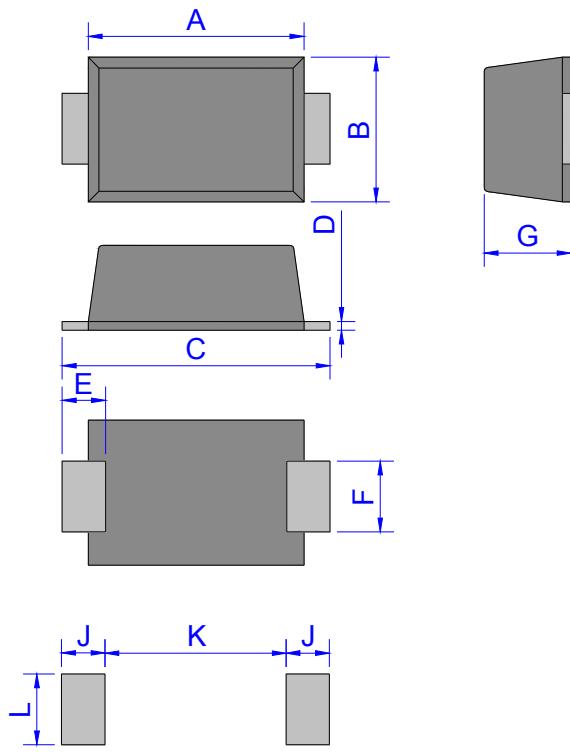


FIG.4: Normalized DC holding current vs. case temperature



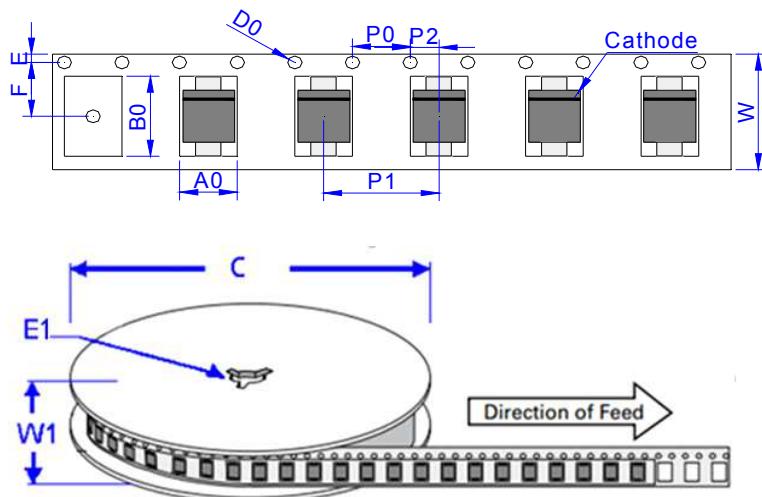
PACKAGE MECHANICAL DATA



SOD-123FL

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	2.60	3.00	0.102	0.118
B	1.60	2.00	0.063	0.079
C	3.45	3.95	0.136	0.156
D	0.10	0.25	0.004	0.01
E	0.3	0.9	0.012	0.035
F	0.80	1.20	0.031	0.047
G	0.95	1.35	0.037	0.053
J	1.30		0.051	
K		1.70		0.067
L	1.30		0.051	

TAPE AND REEL SPECIFICATION-SOD-123FL



Ref.	Dimensions	
	Millimeters	Inches
A0	1.95 ± 0.3	0.077± 0.012
B0	3.95 ± 0.3	0.156 ± 0.012
C	178	7.0
D0	1.55 ± 0.1	0.061 ± 0.004
E	1.75 ± 0.2	0.069 ± 0.008
E1	13.3 ± 0.3	0.524± 0.012
F	3.50 ± 0.2	0.138 ± 0.008
P0	4.00 ± 0.2	0.157 ± 0.008
P1	4.00 ± 0.2	0.157 ± 0.008
P2	2.00 ± 0.2	0.079 ± 0.008
W	8.0± 0.2	0.315 ± 0.008
W1	11.5 ± 1.0	0.453 ± 0.039

PART No.	UNIT WEIGHT (g/PCS) typ.	PACKAGE	REEL (PCS)	DESCRIPTION
P0641DM	0.0141	SOD-123FL	3000	7 inch reel pack

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